

PTO/SB/08A

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

Sheet 1 of 4

Application Number.:

Unassigned

Filing Date:

Herewith

First Named Inventor:

Toshiharu Furukawa

Art Unit:

Unassigned

Examiner Name:

Unassigned

Attorney Docket Number.:

ROC920030268US1**U.S. PATENT DOCUMENTS**

Examiner Initials*	Cite No. ¹	Document Number Number - Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns or Lines Where Relevant Passages or Figs. Appear
ON		US - 6,423,583 B1	07-23-2002	Avouris et al.	
		US - 6,515,325 B1	02-04-2003	Farnworth et al.	
		US - 2003/0168683 A1	09-11-2003	Farnworth et al.	
		US - 2003/0170930 A1	09-11-2003	Choi et al.	
ON		US - 2003/0178617 A1	09-25-2003	Appenzeller et al.	
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FOREIGN PATENT DOCUMENTS

Examiner Initials	Cite No. ¹	Foreign Patent Document Country ³ - Number ⁴ - Kind Code ⁵ Code (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns or Lines Where Relevant Passages or Figs. Appear	T ⁶

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⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language translation is attached.

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Sheet 2 of 4

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ROC920030268US1**OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS**

Examiner Initials	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and or country where published.	T ²
ON		P. HARRIS, "Carbon Nanotubes and Related Structures," Cambridge University Press, 1999.	
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Sheet 3 of 4

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 Examiner Name: Unassigned
 Attorney Docket Number.: ROC920030268US1

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

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		P. COLLINS et al., "Nanotubes for Electronics," Scientific American, December 2000, pp. 62-69.	
		S. J. WIND et al., "Vertical Scaling of Carbon Nanotube Field-Effect Transistors Using Top Gate Electrodes," Applied Physics Letters, Volume 80, Number 20, May 20, 2002, pp. 3817-3819.	
		Z. F. REN et al., "Growth, Characterization, and Potential Applications of Periodic Carbon Nanotube Arrays," Department of Physics, Boston College, updated 2001.	
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		Z. HUANG et al., "Growth of Highly Oriented Carbon Nanotubes by Plasma-Enhanced Hot Filament Chemical Vapor Deposition," Applied Physics Letters, Volume 73, Number 26, December 28, 1998, pp. 3845-3847.	
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